

# PCTEST ENGINEERING LABORATORY, INC.

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# **HEARING AID COMPATIBILITY**

**Applicant Name:** 

Samsung Electronics Co., Ltd. 129, Samsung-ro, Maetan dong, Yeongtong-gu, Suwon-si Gyeonggi-do 16677, Korea

**Date of Testing:** 01/18/2016 - 01/22/2016 **Test Site/Location:** PCTEST Lab, Columbia, MD, USA **Test Report Serial No.:** 0Y1601290229.A3L

FCC ID: A3LSMG930US

APPLICANT: SAMSUNG ELECTRONICS CO., LTD.

Scope of Test: RF Emissions Testing **Application Type:** Class II Permissive Change

FCC Rule Part(s): CFR §20.19(b) **HAC Standard:** ANSI C63.19-2011

CTIA Test Plan for Hearing Aid Compatibility Rev 3.0, November 2013

**EUT Type:** Portable Handset

Model(s): SM-G930V, SM-G930A, SM-G930T, SM-G930R4, SM-G930P

**Test Device Serial No.:** Pre-Production Sample [S/N: 07060] Class II Permissive Change(s): Adding Wireless Charging Battery Cover

02/03/2016 **Original Grant Date:** 

This report pertains only to the evaluation of the Wireless Charging Battery Cover (WCBC). Please refer to the HAC RFE Report S/N: 0Y1512012044.A3L for the complete original compliance. This wireless portable device, with the use of the additional accessory, has been shown to be hearing-aid compatible as specified in ANSI/IEEE Std. C63.19-2011 and has been tested in accordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.









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#### INTRODUCTION 1.

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-86581 to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

# **Compatibility Tests Involved:**

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.



Figure 1-1 Hearing Aid in-vitu

<sup>&</sup>lt;sup>1</sup> FCC Rule & Order, WT Docket 01-309 RM-8658

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# 2. TEST SITE LOCATION

#### I. Introduction

The map at the right shows the location of the PCTEST LABORATORY in Columbia, Maryland. It is in proximity to the FCC Laboratory, the Baltimore-Washington International (BWI) airport, the city of Baltimore and Washington, DC (See Figure 2-1).

These measurement tests were conducted at the PCTEST Engineering Laboratory, Inc. facility in Stonewood Business Center, Guilford Industrial Park, Columbia, Maryland. The site address is 7185 Oakland Mills Road, Columbia, MD 21046. The test site is one of the highest points in the Columbia area with an elevation of 390 feet above mean sea level. The site coordinates are 39° 10' 24" N latitude and 76° 49' 50" W longitude. The facility is 0.4 miles North of the FCC laboratory, and the ambient signal and ambient signal strength are approximately equal to those of the FCC laboratory.

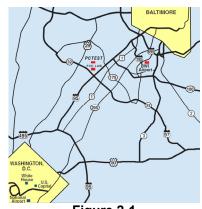


Figure 2-1
Map of the Greater Baltimore and Metropolitan
Washington, D.C. area

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#### **EUT DESCRIPTION** 3.



FCC ID: A3LSMG930US

Manufacturer: Samsung Electronics Co., Ltd.

129, Samsung-ro, Maetan dong,

Yeongtong-gu, Suwon-si Gyeonggi-do 16677, Korea

SM-G930V, SM-G930A, SM-G930T, SM-G930R4, SM-G930P Model(s):

Serial Number: 07060

Antenna Configurations: Internal Antenna

**HAC Test Configurations:** GSM 1900, 512, BT Off, WLAN Off, LTE Off

**EUT Type:** Portable Handset

Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Voice over Digital Transport OTT Capability	WIFI Low Power	Additional GSM Power Reduction
GSM	850 1900	vo	Yes <sup>3</sup>	Yes: WIFI or BT	N/A	N/A	No
	GPRS/EDGE	DT	No	Yes: WIFI or BT	Yes	N/A	No
UMTS	850 1900	VD	No <sup>1,3</sup>	Yes: WIFI or BT	N/A	N/A	N/A
	HSPA	DT	No	Yes: WIFI or BT	Yes	N/A	N/A
CDMA	835 1900	vo	Yes <sup>3</sup>	Yes: WIFI or BT	N/A	N/A	N/A
	EVDO	DT	No	Yes: WIFI or BT	Yes	N/A	N/A
LTE (FDD)	780 (B13) 850 (B5) 1700 (B4) 1900 (B2)	VD <sup>2</sup>	No <sup>1,3</sup>	Yes: WIFI or BT	Yes	N/A	N/A
WIFI	2450 5200 5300 5500 5800	VD	No <sup>1,3</sup>	Yes: CDMA, GSM, UMTS, or LTE	Yes	N/A	N/A
BT	2450	DT	No	Yes: CDMA. GSM. UMTS. or LTE	N/A	N/A	N/A
Service		ed for CMRS	Notes:  1. Evaluated for MIF and low-power exemption.  2. The 3GPP VoLTE CMRS service is defined by GSMA in PRD IR.92 for IP Voice Service and Digital Transport.  3. GSM850, UMTS, CDMA, LTE and WIFI are not within the scope of this test report. Please refer to the appropriate test reports.				

Table 3-1: SM-G930V HAC Air Interfaces

Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Voice over Digital Transport OTT Capability	WIFI Low Power	Additional GSM Power Reduction
GSM	850 1900	VO	Yes <sup>3</sup>	Yes: WIFI or BT	N/A	N/A	No
	GPRS/EDGE	DT	No	Yes: WIFI or BT	Yes	N/A	No
UMTS	850 1700 1900	VD	No <sup>1,3</sup>	Yes: WIFI or BT	N/A	N/A	N/A
l	HSPA	DT	No	Yes: WIFI or BT	Yes	N/A	N/A
LTE (FDD)	700 (B12) 850 (B5) 1700 (B4) 1900 (B2) 2300 (B30)	VD <sup>2</sup>	No <sup>1,3</sup>	Yes: WIFI or BT	Yes	N/A	N/A
WIFI	2450 5200 5300 5500 5800	VD	No <sup>1,3</sup>	Yes: GSM, UMTS, or LTE	Yes	N/A	N/A
BT	2450	DT	No	Yes: GSM, UMTS, or LTE	N/A	N/A	N/A
Type Transpor VO = Voice On			Notes: 1. Evaluated for	MIF and low-power exemption.			_

DT = Digital Data - Not intended for CMRS

- 2. The 3GPP VolTE CMRS service is defined by GSMA in PRD IR.92 for IP Voice Service and Digital Transport.
- Service
  VD = CMRS and Data Transport 3. GSM850, UMTS, LTE and WIFI are not within the scope of this test report. Please refer to the appropriate test reports.

Table 3-2: SM-G930A HAC Air Interfaces

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(MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Voice over Digital Transport OTT Capability	WIFI Low Power	Additional GSM Power Reduction	
850 1900	vo	Yes <sup>3</sup>	Yes: WIFI or BT	N/A	N/A	No	
GPRS/EDGE	DT	No	Yes: WIFI or BT	Yes	N/A	No	
850 1700 1900	VD	No <sup>1,3</sup>	Yes: WIFI or BT	N/A	N/A	N/A	
HSPA	DT	No	Yes: WIFI or BT	Yes	N/A	N/A	
700 (B12) 850 (B5) 1700 (B4) 1900 (B2)	VD <sup>2</sup>	No <sup>1,3</sup>	Yes: WIFI or BT	Yes	N/A	N/A	
2450 5200 5300 5500 5800	VD	No <sup>1,3</sup>	Yes: GSM, UMTS, or LTE	Yes	N/A	N/A	
2450	DT	No	Yes: GSM, UMTS, or LTE	N/A	N/A	N/A	
Type Transport VO = Voice Only DT = Digital Data - Not intended for CMRS Service			Notes:  1. Evaluated for MIF and low-power exemption.  2. The 3GPP VoLTE CMRS service is defined by GSMA in PRD IR.92 for IP Voice Service and Digital Transport.  3. GSM850, UMTS, LTE and WIFI are not within the scope of this test report. Please refer to the appropriate test reports.				
	850 1900 GPRS/EDGE 850 1700 1900 HSPA 700 (B12) 850 (B5) 1700 (B4) 1900 (B2) 2450 5200 5300 5500 5800 2450	850 VO 1900 VO 6PRS/EDGE DT 850 1700 VD 1900 HSPA DT 700 (B12) 850 (B5) 1700 (B2) 2450 5200 5300 VD 5500 5800 2450 DT	S50	Residence   Resi	S50	SSO	

# Table 3-3: SM-G930T HAC Air Interfaces

Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Voice over Digital Transport OTT Capability	WIFI Low Power	Additional GSM Power Reduction
GSM	850 1900	VO	Yes <sup>2</sup>	Yes: WIFI or BT	N/A	N/A	No
	GPRS/EDGE	DT	No	Yes: WIFI or BT	Yes	N/A	No
UMTS	850 1900	VD	No <sup>1,2</sup>	Yes: WIFI or BT	N/A	N/A	N/A
	HSPA	DT	No	Yes: WIFI or BT	Yes	N/A	N/A
CDMA	835 1900	VO	Yes <sup>2</sup>	Yes: WIFI or BT	N/A	N/A	N/A
	EVDO	DT	No	Yes: WIFI or BT	Yes	N/A	N/A
LTE (FDD)	700 (B12) 780 (B13) 850 (B5) 1700 (B4) 1900 (B2) 1900 (B25)	DT	No	Yes: WIFI or BT	Yes	N/A	N/A
WIFI	2450 5200 5300 5500 5800	DT	No	Yes: CDMA, GSM, UMTS, or LTE	Yes	N/A	N/A
BT	2450	DT	No	Yes: CDMA. GSM. UMTS. or LTE	N/A	N/A	N/A
Service				MIF and low-power exemption. TS and CDMA are not within the scope of t	this test report. Please refer to	the approp	riate test reports.

# Table 3-4: SM-G930R4 HAC Air Interfaces

Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Voice over Digital Transport OTT Capability	WIFI Low Power	Additional GSM Power Reduction
GSM	850 1900	VO	Yes <sup>2</sup>	Yes: WIFI or BT	N/A	N/A	No
	GPRS/EDGE	DT	No	Yes: WIFI or BT	Yes	N/A	No
UMTS	850 1900	VD	No <sup>1,2</sup>	Yes: WIFI or BT	N/A	N/A	N/A
	HSPA	DT	No	Yes: WIFI or BT	Yes	N/A	N/A
CDMA	835 1900	VO	Yes <sup>2</sup>	Yes: WIFI or BT	N/A	N/A	N/A
	EVDO	DT	No	Yes: WIFI or BT	Yes	N/A	N/A
LTE (FDD)	700 (B12) 850 (B5) 1700 (B4) 1900 (B2) 850 (B26) 1900 (B25)	DT	No	Yes: WIFI or BT	Yes	N/A	N/A
LTE (TDD)	2600 (B41)	DT	No	Yes: WIFI or BT	Yes	N/A	N/A
WIFI	2450 5200 5300 5500 5800	VD	No <sup>1,2</sup>	Yes: CDMA, GSM, UMTS, or LTE	Yes	N/A	N/A
BT	2450	DT	No	Yes: CDMA. GSM. UMTS. or LTE	N/A	N/A	N/A
Service		ed for CMRS		MIF and low-power exemption. TS, CDMA, and WIFI are not within the sco	ope of this test report. Please r	efer to the a	appropriate test reports.

# Table 3-5: SM-G930P HAC Air Interfaces

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# 4. ANSI/IEEE C63.19 PERFORMANCE CATEGORIES

# I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters			
Near field Category	E-field emissions CW dB(V/m)			
	f < 960 MHz			
M1	50 to 55			
M2	45 to 50			
M3	40 to 45			
M4	< 40			
	f > 960 MHz			
M1	40 to 45			
M2	35 to 40			
M3	30 to 35			
M4	< 30			
WD near-field ca	Table 4-1 WD near-field categories as defined in ANSI C63.19-2011			

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# 5. SYSTEM SPECIFICATIONS

#### **ER3DV6 E-Field Probe Description**

Construction: One dipole parallel, two dipoles normal to probe axis

Built-in shielding against static charges

Calibration: In air from 100 MHz to 3.0 GHz

(absolute accuracy ±6.0%, k=2)

Frequency: 100 MHz to > 6 GHz;

Linearity: ± 0.2 dB (100 MHz to 3 GHz)

Directivity  $\pm 0.2$  dB in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

Dynamic Range 2 V/m to > 1000 V/m

(M3 or better device readings fall well below diode

compression point)

Linearity: ± 0.2 dB

Dimensions Overall length: 330 mm (Tip: 16 mm)

Tip diameter: 8 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 2.5 mm



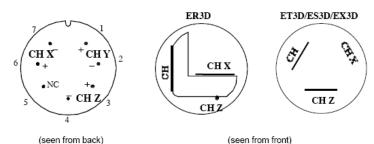
Figure 5-1 E-field Free-space Probe

#### **Probe Tip Description**

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

The electric field probes have an irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement"). Their geometric center is at 2.5mm from the tip, and the element ends are 1.1mm closer to the tip.

#### Connector Plan



The antistatic shielding inside the probe is connected to the probe connector case.

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#### **Instrumentation Chain**

## **Equation 1**

# Conversion of Connector Voltage u, to E-Field E,

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF)/(DCP)}{Norm_i \cdot ConvF}}$$

whereby

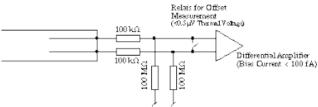
E<sub>i</sub>: electric field in V/m

 $u_i$ : voltage of channel i at the connector in  $\mu V$ Norm: sensitivity of channel i in  $\mu V/(V/m)^2$ enhancement factor in liquid (ConvF=1 for Air)

DCP: diode compression point in  $\mu V$ 

CF: signal crest factor (peak power/average power)

#### Conditions of Calibration

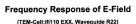


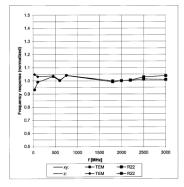
Please note

- a lower input impedance of the amplifier will result in different sensitivity factors Norm, and DCP
- · larger bias currents will cause higher offset

## **Probe Response to Frequency**

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).





Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

Figure 5-2 E-Field Probe Frequency Response

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#### **SPEAG Robotic System**

E-field measurements are performed using the DASY5 automated dosimetric assessment system. The DASY5 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland and consists of high precision robotics system (Staubli), robot controller, Intel CORE i7 computer, nearfield probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).



Figure 5-3 SPEAG Robotic System

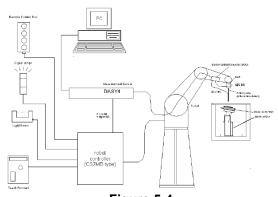
# **System Hardware**

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the computer with operating system and RF Measurement Software DASY5 v52.8 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

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#### **System Electronics**

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.



**Figure 5-4** SPEAG Robotic System Diagram

#### **DASY5 Instrumentation Chain**

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$V_i = U_i + U_i^2 \cdot \frac{cf}{dcp_i}$$

 $\begin{array}{lll} \text{with} & V_i & = \text{compensated signal of channel i} & (i = x, y, z) \\ & U_i & = \text{input signal of channel i} & (i = x, y, z) \\ & cf & = \text{crest factor of exciting field} & (\text{DASY parameter}) \\ & dcp_i & = \text{diode compression point} & (\text{DASY parameter}) \end{array}$ 

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From the compensated input signals the primary field data for each channel can be evaluated:

$$\mathbf{E} - \text{fieldprobes}: \qquad E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}}$$

with  $V_i$  = compensated signal of channel i  $Norm_i$  = sensor sensitivity of channel i (i = x, y, z)(i = x, y, z)

 $\mu V/(V/m)^2$  for E-field Probes

= sensitivity enhancement in solution

= electric field strength of channel i in V/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500ms and a probe response time of <5 ms. In the current implementation, DASY5 waits longer than 100ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

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# 6. TEST PROCEDURE

#### I. RF EMISSIONS

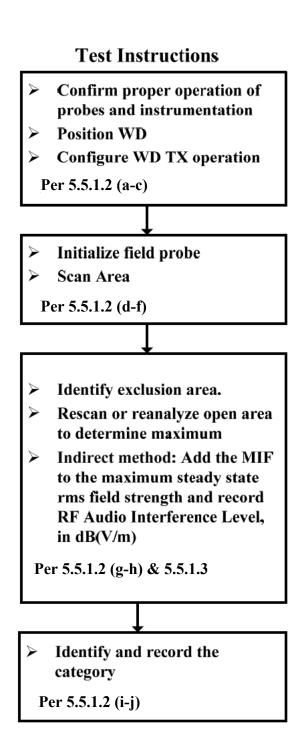


Figure 6-1 RF Emissions Flow Chart

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#### **Test Setup**

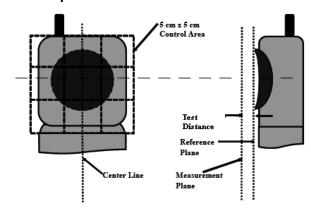


Figure 6-2
E-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)

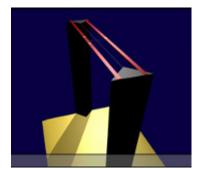


Figure 6-3 HAC Phantom

#### **RF Emissions Test Procedure:**

The following illustrate a typical RF emissions test scan over a wireless communications device:

- 1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
- 2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.
- 3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.
- 4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.
- 5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.
- 6. The measurement system measured the field strength at the reference location.
- 7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. A 360° rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.
- 8. The system performed a drift evaluation by measuring the field at the reference location. If the power drift deviated by more than 5%, the HAC test and drift measurements were repeated.

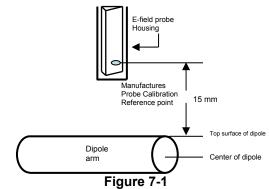
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# 7. SYSTEM CHECK

# I. System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 15 mm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:



Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device [e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (20dBm) RMS] after adjustment for any mismatch.

## II. Validation Procedure

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

The length of the dipole was scanned, and the average peak value was recorded.

## **Measurement of CW**

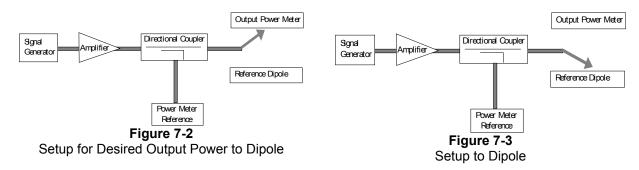
Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

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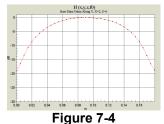
REV 3.1.M

RF power was recorded using both an average and a peak power reading meter.



Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 7-3.

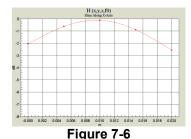
The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:



2-D Raw Data from scan along dipole axis



Figure 7-5
2-D Interpolated points from scan along dipole axis



2-D Raw Data from scan along transverse axis



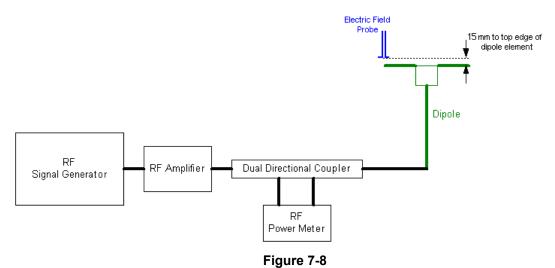
2-D Interpolated points from scan along transverse axis

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# **III. System Check Results**

# **Validation Results**

Frequency (MHz)	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation
1880	1137	20.0	92.7	89.7	3.3%



System Check Setup

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#### **OVERALL MEASUREMENT SUMMARY** 8.

FCC ID:	A3LSMG930US
Model:	SM-G930V, SM-G930A, SM-G930T, SM-G930R4, SM-G930P
S/N:	07060

# I. E-FIELD EMISSIONS:

Table 8-1 **HAC Data Summary for E-field** 

	11/10 Bata Gaillinary for E flora										
Mode	Channel	Battery Cover	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 5.5
E-field Emis	sions										
GSM1900	512	WCBC - Inactive	Acoustic	9.20	19.28	3.51	22.79	35.00	-12.21	M4	none
GSM1900	512	WCBC - Active	Acoustic	12.03	21.61	3.51	25.12	35.00	-9.88	M4	none

The overall worst case configuration from the original filing was evaluated using the Wireless Charging Battery Cover. Prior to measurement with the accessory, MIF values and conducted powers of the host device were verified against the results in the original filing.

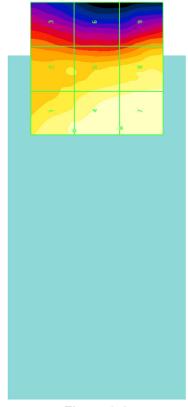


Figure 8-1 Sample E-field Scan Overlay (See Test Setup Photographs for actual WD overlay)

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FCC ID:	A3LSMG930US
Model:	SM-G930V, SM-G930A, SM-G930T, SM-G930R4, SM-G930P
S/N:	07060

# II. Worst-case Configuration Evaluation

Table 8-2
Peak Reading 360° Probe Rotation at Azimuth axis

	1 can reading 500 1 100c retation at Azimuth axis										
Mode	Channel	Battery Cover	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	
Probe Rotatio	Probe Rotation at Worst-Case										
GSM1900	512	WCBC - Active	Acoustic	12.53	21.96	3.51	25.47	35.00	-9.53	M4	

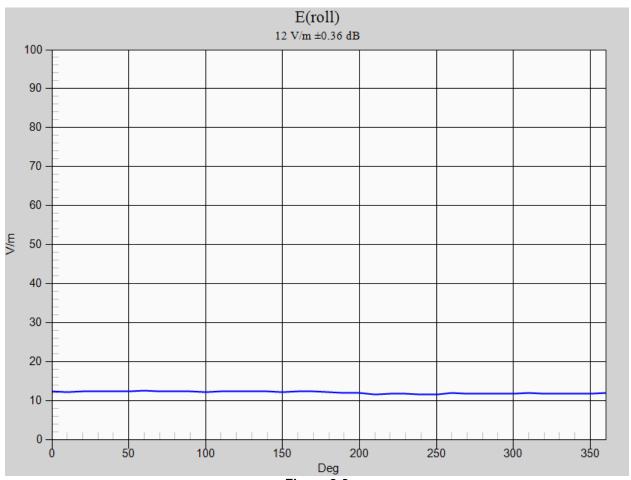


Figure 8-2
Worst-Case Probe Rotation about Azimuth axis

<sup>\*</sup> Note: Locations of probe rotation (with and without exclusions) are shown in Figure 8-1 denoted by the green square markers.

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#### EQUIPMENT LIST 9.

Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
Agilent	E4432B	ESG-D Series Signal Generator	3/16/2015	Annual	3/16/2016	US40053896
Agilent	N5182A	MXG Vector Signal Generator	3/16/2015	Annual	3/16/2016	MY47420651
Amplifier Research	15S1G6	Amplifier	N/A	CBT*	N/A	433978
Anritsu	MA24106A	USB Power Sensor	5/29/2015	Annual	5/29/2016	1248508
Anritsu	MA24106A	USB Power Sensor	3/3/2015	Annual	3/3/2016	1349501
Mini-Circuits	NLP-1200+	Low Pass Filter DC to 1000 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	BW-N20W5	Power Attenuator	N/A	CBT*	N/A	1226
Mini-Circuits	NLP-2950+	Low Pass Filter DC to 2700 MHz	N/A	CBT*	N/A	N/A
Pasternack	PE2237-20	Bidirectional Coupler	N/A	CBT*	N/A	N/A
Pasternack	NC-100	Torque Wrench	5/21/2015	Biennial	5/21/2017	N/A
Rohde & Schwarz	CMU200	Base Station Simulator	12/2/2015	Annual	12/2/2016	833855/0010
SPEAG	ER3DV6	Freespace E-field Probe	8/24/2015	Annual	8/24/2016	2335
SPEAG	AIA	Audio Interference Analzyer	N/A	CBT*	N/A	1010
SPEAG	CD1880V3	Freespace 1880 MHz Dipole	2/17/2015	Biennial	2/17/2017	1137
SPEAG	DAE4	Dasy Data Acquisition Electronics	11/11/2015	Annual	11/11/2016	1334

Table 9-1 **Equipment List** 

Calibration traceable to the National Institute of Standards and Technology (NIST).

\*Note: CBT (Calibrated Before Testing). Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

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# 10. MEASUREMENT UNCERTAINTY

Wireless Communications Device Near-Field Measurement Uncertainty Estimation								
Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Ci (E)	Unc. (dB)	Notes/Comments	
Measurement System								
RF System Reflections	0.50	Tolerance	N	1.00	1	0.50	* Refl. < -20 dB	
Field Probe Calibration	0.21	Tolerance	N	1.00	1	0.21		
Field Probe Isotropy	0.01	Tolerance	N	1.00	1	0.01		
Field Probe Frequency Response	0.135	Tolerance	N	1.00	1	0.14		
Field Probe Linearity	0.013	Tolerance	N	1.00	1	0.01		
Modulation Interference Factor	0.20	Tolerance	R	1.73	1	0.12	Applicable for M-rating testing	
Boundary Effects	0.105	Accuracy	R	1.73	1	0.06	*	
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.12	*	
Probe Positioner	0.050	Accuracy	R	1.73	1	0.03	*	
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	0.03	*	
Resolution to 2mm error	0.21	Tolerance	N	1.00	1	0.21		
System Detection Limit	0.05	Tolerance	R	1.73	1	0.03	*	
Readout Electronics	0.015	Tolerance	N	1.00	1	0.02	*	
Integration Time	0.11	Tolerance	R	1.73	1	0.06	*	
Response Time	0.033	Tolerance	R	1.73	1	0.02	*	
Phantom Thickness	0.10	Tolerance	R	1.73	1	0.06	*	
System Repeatability (Field x 2=power)	0.17	Tolerance	N	1.00	1	0.17	*	
Test Sample Related								
Device Positioning Vertical	0.2	Tolerance	R	1.73	1	0.12	*	
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	0.03	*	
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	0.06	*	
Power Drift	0.21	Tolerance	R	1.73	1	0.12		
Combined Standard Uncertainty (k=1)						0.66	16.3%	
Expanded Uncertainty [95% confidence]						1.31	32.6%	
Expanded Uncertainty [95% confidence]	on Field					0.66	16.3%	

# Table 10-1 Uncertainty Estimation Table

#### Notes:

- Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All
  equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81
  and NIST Tech Note 1297 and UKAS M3003.
- 2. \* Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurement uncertainty. Another component of the overall uncertainty is based on the variability of repeated measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurement results with that of the instrumentation chain using the technique contained in NIS 81 and NIS 3003, the overall measurement uncertainty was estimated.

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# 11. TEST DATA

See following Attached Pages for Test Data.

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## **DUT: CD1880V3 - SN1137**

Type: CD1880V3 Serial: 1137

#### Communication System: CW; Frequency: 1880 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2335; Calibrated: 08/24/2015
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn1334; Calibrated: 11/11/2015
- Phantom: HAC Test Arch with AMCC, Center; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (8);

#### 1880 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

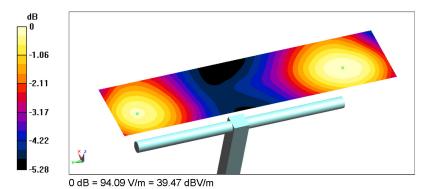
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 167.1 V/m; Power Drift = 0.05 dB

Applied MIF = 0.00 dB

Average Value of Peak (interpolated) = 92.7 V/m



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Date: 01/22/2016



#### **DUT: A3LSMG930US**

Type: Portable Handset Serial: 07060 Backlight off Duty Cycle: 1:8.3

#### Communication System: GSM; Frequency: 1850.2 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2335; Calibrated: 08/24/2015
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1334; Calibrated: 11/11/2015
- Phantom: HAC Test Arch with AMCC, Center, Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (8);

# GSM1900 Low Channel, Wireless Charging Battery Cover - Active /Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 11.80 V/m; Power Drift = 0.14 dB

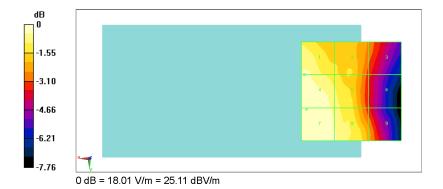
Applied MIF = 3.51 dB

RF audio interference level = 25.12 dBV/m

Emission category: M4

#### MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 <b>M4</b>
24.67 dBV/m	23.82 dBV/m	22.45 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
25.11 dBV/m	24.41 dBV/m	21.8 dBV/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>
25.11 dBV/m	24.68 dBV/m	22.83 dBV/m



#### 2016 PCTEST

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# 12. CALIBRATION CERTIFICATES

The following pages include the probe calibration used to evaluate HAC for the DUT.

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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland

**PC Test** 

Client





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Certificate No: ER3-2335\_Aug15/2

# CALIBRATION CERTIFICATE (Replacement of No: ER3-2335\_Aug15)

Object ER3DV6 - SN:2335

Calibration procedure(s) QA CAL-02.v8, QA CAL-25.v6

Calibration procedure for E-field probes optimized for close near field

evaluations in air

Calibration date: August 24, 2015

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).

The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	01-Apr-15 (No. 217-02128)	Mar-16
Power sensor E4412A	MY41498087	01-Apr-15 (No. 217-02128)	Mar-16
Reference 3 dB Attenuator	SN: S5054 (3c)	01-Apr-15 (No. 217-02129)	Mar-16
Reference 20 dB Attenuator	SN: S5277 (20x)	01-Apr-15 (No. 217-02132)	Mar-16
Reference 30 dB Attenuator	SN: S5129 (30b)	01-Apr-15 (No. 217-02133)	Mar-16
Reference Probe ER3DV6	SN: 2328	08-Oct-14 (No. ER3-2328_Oct14)	Oct-15
DAE4	SN: 789	16-Mar-15 (No. DAE4-789_Mar15)	Mar-16
1			
Secondary Standards	ID	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Apr-13)	In house check: Apr-16
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-14)	In house check: Oct-15

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Issued: September 22, 2015
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#### Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst Service suisse d'étalonnage С Servizio svizzero di taratura Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Glossarv:

NORMx,y,z DCP

sensitivity in free space diode compression point

CF A, B, C, D

crest factor (1/duty\_cycle) of the RF signal modulation dependent linearization parameters

Polarization φ

φ rotation around probe axis

Polarization 9

9 rotation around an axis that is in the plane normal to probe axis (at measurement center),

i.e., 9 = 0 is normal to probe axis

Connector Angle

information used in DASY system to align probe sensor X to the robot coordinate system

- Calibration is Performed According to the Following Standards:

  a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005
  - CTIA Test Plan for Hearing Aid Compatibility, Rev 3.0, November 2013

# Methods Applied and Interpretation of Parameters:

- NORMx, y, z: Assessed for E-field polarization  $\theta = 0$  for XY sensors and  $\theta = 90$  for Z sensor (f  $\leq 900$  MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- $NORM(f)x,y,z = NORMx,y,z * frequency_response$  (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z; Dx,y,z; VRx,y,z: A, B, C, D are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no uncertainty required).

Certificate No: ER3-2335\_Aug15/2

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ER3DV6 – SN:2335 August 24, 2015

# Probe ER3DV6

SN:2335

Manufactured: Calibrated:

September 9, 2003 August 24, 2015

Calibrated for DASY/EASY Systems (Note: non-compatible with DASY2 system!)

Certificate No: ER3-2335\_Aug15/2

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ER3DV6 - SN:2335 August 24, 2015

# DASY/EASY - Parameters of Probe: ER3DV6 - SN:2335

#### **Basic Calibration Parameters**

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm $(\mu V/(V/m)^2)$	1.65	1.67	1.88	± 10.1 %
DCP (mV) <sup>B</sup>	100.3	99.3	100.2	

#### **Modulation Calibration Parameters**

UID	Communication System Name		Α	В	С	D	VR	Unc≝
			dB	dB√μV		dB	m۷	(k=2)
0	CW	Х	0.0	0.0	1.0	0.00	203.0	±3.3 %
		Y	0.0	0.0	1.0		160.6	
		Z	0.0	0.0	1.0		203.5	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

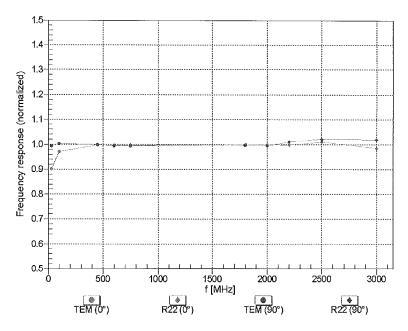
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B Numerical linearization parameter: uncertainty not required.
E Uncertainty is determined using the max, deviation from linear response applying rectangular distribution and is expressed for the square of the

ER3DV6 - SN:2335 August 24, 2015

# Frequency Response of E-Field (TEM-Cell:ifi110 EXX, Waveguide: R22)



Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

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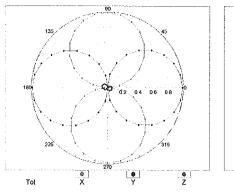
FCC ID: A3LSMG930US	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
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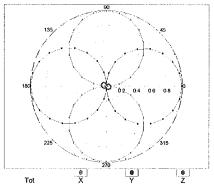
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# Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$

f=600 MHz,TEM,0°

f=2500 MHz,R22,0°

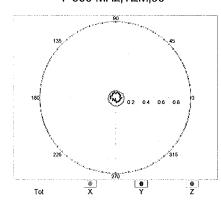


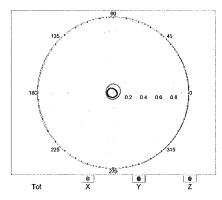


# Receiving Pattern ( $\phi$ ), $\theta$ = 90°

f=600 MHz,TEM,90°

f=2500 MHz,R22,90°





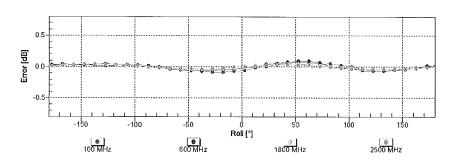
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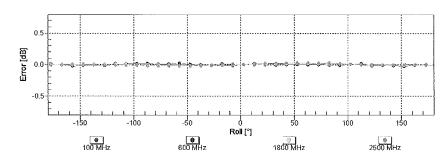
ER3DV6 - SN:2335 August 24, 2015

# Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

# Receiving Pattern ( $\phi$ ), $\vartheta = 90^{\circ}$



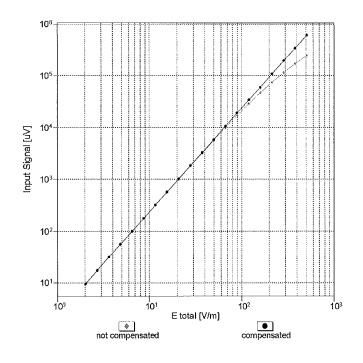
Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

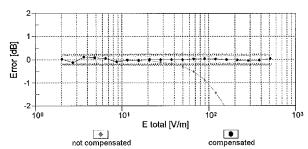
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# Dynamic Range f(E-field) (TEM cell , f = 900 MHz)





Uncertainty of Linearity Assessment: ± 0.6% (k=2)

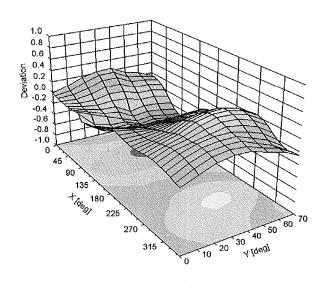
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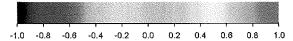
FCC ID: A3LSMG930US	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
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ER3DV6 – SN:2335 August 24, 2015

# **Deviation from Isotropy in Air**

Error (φ, θ), f = 900 MHz





Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

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# DASY/EASY - Parameters of Probe: ER3DV6 - SN:2335

#### **Other Probe Parameters**

Sensor Arrangement	Rectangular
Connector Angle (°)	82.7
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8 mm
Probe Tip to Sensor X Calibration Point	2,5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm
	1

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#### Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Client

**PC Test** 

Certificate No: CD1880V3-1137\_Feb15

#### CALIBRATION CERTIFICATE CD1880V3 - SN: 1137 Object QA CAL-20.v6 Calibration procedure(s) Calibration procedure for dipoles in air 3/16/15 February 17, 2015 Calibration date: This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate. All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%. Calibration Equipment used (M&TE critical for calibration) Primary Standards Cal Date (Certificate No.) Scheduled Calibration Power meter EPM-442A GB37480704 07-Oct-14 (No. 217-02020) Oct-15 Power sensor HP 8481A US37292783 07-Oct-14 (No. 217-02020) Oct-15 Power sensor HP 8481A MY41092317 07-Oct-14 (No. 217-02021) Oct-15 Reference 10 dB Attenuator Apr-15 SN: 5047.2 / 06327 03-Apr-14 (No. 217-01921) Probe ER3DV6 SN: 2336 31-Dec-14 (No. ER3-2336\_Dec14) Dec-15 31-Dec-14 (No. H3-6065 Dec14) Probe H3DV6 SN: 6065 Dec-15 12-Sep-14 (No. DAE4-781\_Sep14) DAE4 SN: 781 Sep-15 Secondary Standards 1D# Check Date (in house) Scheduled Check Power meter Agilent 4419B SN: GB42420191 09-Oct-09 (in house check Sep-14) In house check: Sep-16 SN: US38485102 In house check: Sep-16 Power sensor HP E4412A 05-Jan-10 (in house check Sep-14) SN: US37295597 Power sensor HP 8482A 09-Oct-09 (in house check Sep-14) In house check: Sep-16 Network Analyzer HP 8753E US37390585 18-Oct-01 (in house check Oct-14) In house check: Oct-15 RF generator R&S SMT-06 SN: 832283/011 27-Aug-12 (in house check Oct-13) In house check: Oct-16 Name Function Calibrated by: Leif Klysner Laboratory Technician Approved by: Fin Bomholt Deputy Technical Manager Issued: February 19, 2015 This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

#### References

 ANSI-C63.19-2011
 American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

#### Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
  (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
   In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
  distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
  figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
  is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
  directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network
  Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was
  eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any
  obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the
coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%

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#### **Measurement Conditions**

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.8.8
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	1730 MHz ± 1 MHz 1880 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

#### Maximum Field values at 1730 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum	
Maximum measured above high end	100 mW input power	98.8 V/m = 39.90 dBV/m	
Maximum measured above low end	100 mW input power	93.2 V/m = 39.39 dBV/m	
Averaged maximum above arm	100 mW input power	96.0 V/m ± 12.8 % (k=2)	

#### Maximum Field values at 1880 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	90.2 V/m = 39.10 dBV/m
Maximum measured above low end	100 mW input power	89.1 V/m = 38.99 dBV/m
Averaged maximum above arm	100 mW input power	89.7 V/m ± 12.8 % (k=2)

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#### Appendix (Additional assessments outside the scope of SCS0108)

#### **Antenna Parameters**

#### **Nominal Frequencies**

Frequency	Return Loss Impe		
1730 MHz	22.8 dB	48.5 Ω + 7.0 jΩ	
1880 MHz	21.6 dB	49.8 Ω + 8.3 jΩ	
1900 MHz	21.7 dB	53.0 Ω + 7.9 jΩ	
1950 MHz	27.3 dB	54.5 Ω - 0.7 jΩ	
2000 MHz	19.7 dB	40.7 Ω - 0.5 jΩ	

#### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

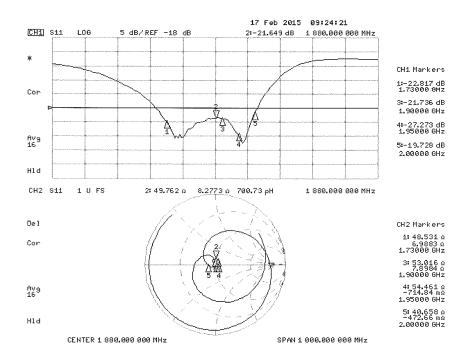
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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#### Impedance Measurement Plot



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#### DASY5 E-field Result

Date: 17.02.2015

Test Laboratory: SPEAG Lab2

#### DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1137

Communication System: UID 0 - CW; Frequency: 1880 MHz, Frequency: 1730 MHz

Medium parameters used:  $\sigma = 0$  S/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

# DASY52 Configuration:

- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 31.12.2014;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 12.09.2014
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.8(1222); SEMCAD X 14.6.10(7331)

#### Dipole E-Field measurement/E-Scan - 1880MHz d=15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid:

dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 145.1 V/m; Power Drift = -0.01 dB
Applied MIF = 0.00 dB
RF audio interference level = 39.10 dBV/m
Emission category: M2

MIF scaled E-field

Grid 1 M2	Grid 2 <b>M2</b>	Grid 3 <b>M2</b>
38.62 dBV/m	38.99 dBV/m	38.92 dBV/m
Grid 4 M2	Grid 5 <b>M2</b>	Grid 6 M2
36.52 dBV/m	36.82 dBV/m	36.81 dBV/m
Grid 7 <b>M2</b>	Grid 8 <b>M2</b>	Grid 9 <b>M2</b>
38.84 dBV/m	39.1 dBV/m	39.07 dBV/m

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Dipole E-Field measurement/E-Scan - 1730MHz d=15mm/Hearing Ald Compatibility Test (41x181x1): Interpolated grid:

dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 158.0 V/m; Power Drift = -0.01 dB

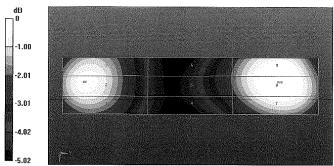
Applied MIF = 0.00 dB

RF audio interference level = 39.90 dBV/m

Emission category: M2

#### MIF scaled E-field

Grid 1 M2	Grid 2 <b>M2</b>	Grid 3 M2
39.02 dBV/m	39.39 dBV/m	39.32 dBV/m
Grid 4 M2	Grid 5 <b>M2</b>	Grid 6 <b>M2</b>
37.42 dBV/m	37.87 dBV/m	37.86 dBV/m
Grid 7 <b>M2</b>	Grid 8 <b>M2</b>	Grid 9 <b>M2</b>
39.53 dBV/m	39.9 dBV/m	39.87 dBV/m



0 dB = 90.20 V/m = 39.10 dBV/m

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# 13. CONCLUSION

The measurements taken in accordance with the procedures provided in the CTIA Test Plan for Hearing Aid Compatibility Rev 3.0, November 2013, indicate that the wireless communications device complies with the HAC limits specified in the ANSI C63.19 Standard and FCC WT Docket No. 01-309 RM-8658. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.

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